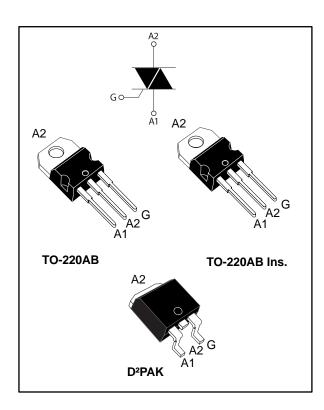


T835H, T850H

High temperature 8 A Snubberless™ Triacs

Datasheet - production data



Features

- Medium current Triac
- 150 °C max. T_j turn-off commutation
- Low thermal resistance with clip bonding
- Very high 3 quadrant commutation capability
- Packages are RoHS (2002/95/EC) compliant
- UL certified (ref. file E81734)

Applications

Especially designed to operate in high power density or universal motor applications such as vacuum cleaner and washing machine drum motor, these 8 A Triacs provide a very high switching capability up to 150 °C junction temperatures.

The heatsink can be reduced, compared to traditional Triac, according to the high performance at given junction temperatures.

Description

Available in through-hole or surface mount packages, these Triacs series are suitable for general purpose mains power ac switching.

By using an internal ceramic pad, they provide voltage insulation (rated at 2500 V_{RMS}).

Table 1: Device summary

Symbol	Value	Unit
I _{T(RMS)}	8	Α
V _{DRM} /V _{RRM}	600	V
lgт	35 or 50	mA

1 Characteristics

Table 2: Absolute ratings (limiting values)

Symbol	Para	neter		Value	Unit
I _{T(RMS)}	RMS on-state current		T _C = 136 °C	8	A
, ,	(full sine wave)	TO-220AB Ins.	T _C = 123 °C		
	Non repetitive surge peak	f = 50 Hz	$t_p = 20 \text{ ms}$	80	
Ітѕм	I _{TSM} on-state current (full cycle, T _j initial = 25 °C)		$t_p = 16.7 \text{ ms}$	84	А
l²t	I ² t value for fusing	$t_p = 10 \text{ ms}$	42	A²s	
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, tr $\leq 100 \text{ ns}$	f = 50 Hz	T _j = 150 °C	50	A/µs
V _{DSM} / V _{RSM}	Non repetitive surge peak off- state voltage $t_p = 10 \text{ ms}$		T _j = 25 °C	V _{DRM} /V _{RRM} + 100	٧
I _{GM}	Peak forward gate current $t_p = 20 \mu s$		T _j = 150 °C	4	Α
P _{G(AV)}	Average gate power dissipation $T_j = 150 \text{ °C}$			1	W
T _{stg}	Storage junction temperature range			-40 to +150	°C
Tj	Operating junction temperature ra	ange		-40 to +150	°C

Table 3: Electrical characteristics ($T_j = 25$ °C unless otherwise specified)

Cumbal	Symbol Test conditions			Value		Unit
Symbol				T835H	T850H	
I _{GT} ⁽¹⁾	$V_D = 12 \text{ V}, R_L = 33 \Omega$	1 - 11 - 111	Max.	35	50	mA
V _G T	VD = 12 V, RL - 33 \(\text{2} \)	1 - 11 - 111	Max.	1.	.0	>
V_{GD}	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$	1 - 11 - 111	Min.	0.15		V
IH ⁽²⁾	I _T = 500 mA		Max.	35	75	mΑ
			N4	50	60	^
I∟	I _G = 1.2 x I _{GT}	II	Max.	80	110	mA
dV/dt ⁽²⁾	$V_D = 2/3 \times V_{DRM}$, gate open	T _j = 150 °C	Min.	1000	1500	V/µs
(dl/dt)c ⁽²⁾	Without snubber	T _j = 150 °C	Min.	11	14	A/ms

 $^{^{(1)}\!}minimum$ IgT is guaranted at 20% of IgT max.

 $[\]ensuremath{^{(2)}}\mbox{for both polarities of A2 referenced to A1.}$

Table 4: Static characteristics

Symbol	Test conditions			Value	Unit
V _T ⁽¹⁾	$I_{TM} = 11 \text{ A}, t_p = 380 \ \mu s$	T _j = 25 °C	Max.	1.5	V
V _{t0} ⁽¹⁾	Threshold voltage	T _j = 150 °C	Max.	0.80	V
R _d ⁽¹⁾	Dynamic resistance	T _j = 150 °C	Max.	52	mΩ
IDRM / IRRM ⁽²⁾	W W	T _j = 25 °C	Max.	5	μΑ
	Vdrm = Vrrm	T _j = 150 °C	Max.	3.1	
	V _D /V _R = 400 V (at peak mains voltage)	T _j = 150 °C	Max.	2.5	mA
	V _D /V _R = 200 V (at peak mains voltage)	T _j = 150 °C	Max.	2.0	

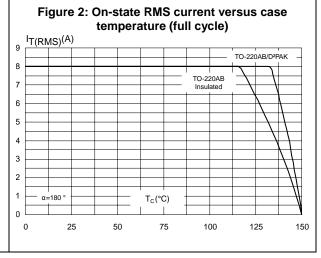
Table 5: Thermal parameters

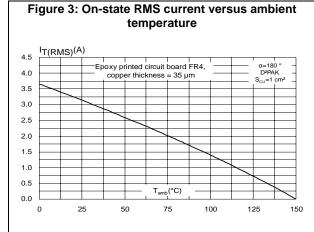
Symbol	Parameter			Unit
D	lunction to cope (AC)	D²PAK, TO-220AB	1.85	
R _{th(j-c)}	Junction to case (AC)	TO-220AB Ins.	3.7	
	Junction to ambient (S _{cu} = 1 cm ²)	D²PAK	45	°C/W
R _{th(j-a)}	Junction to ambient	TO-220AB, TO-220AB Ins.	60	

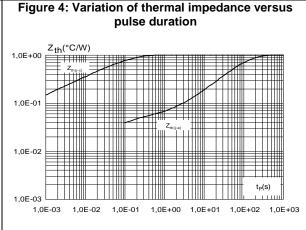
 $^{^{(1)}}$ for both polarities of A2 referenced to A1

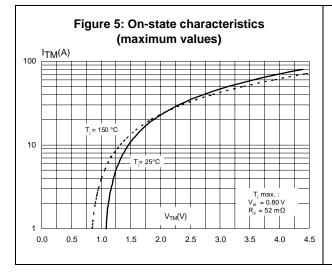
 $^{^{(2)}}t_{p}$ = 380 μs

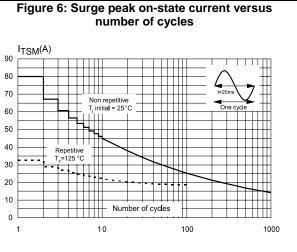
1.1 Characteristics (curves)











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0.01

current for a sinusoidal pulse

10000

Trsm(A)

1000

d/dt limitation: 50 A/µs

Figure 7: Non-repetitive surge peak on-state

Figure 8: Relative variation of I_{GT}, I_H, I_L versus junction temperature (typical values)

2.5

| GT, I_H, I_L [T_j] / I_{GT}, I_H, I_L [T_j= 25°C]

1.0

0.5

0.0

-40 -20 0 20 40 60 80

10.00

Figure 9: Relative variation of critical rate of decrease of main current (dl/dt)c versus reapplied (dV/dt)c

1.00

0.10

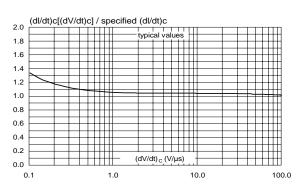


Figure 10: Relative variation of critical rate of decrease of main current versus junction temperature

T_i(°C)

100 120

140 160

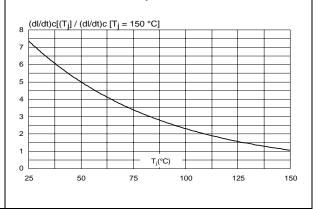


Figure 11: Leakage current versus junction temperature for different values of blocking voltage (typical values)

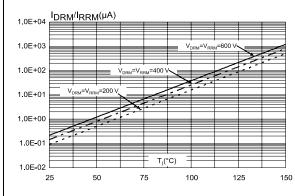
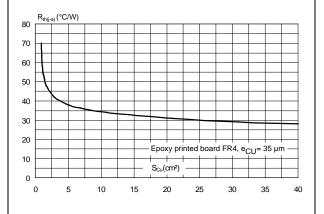


Figure 12: Variation of thermal resistance junction to ambient versus copper surface under tab



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

- Epoxy meets UL94, V0
- Lead-free package leads
- Cooling method: by conduction (C)

2.1 D²PAK package information

Figure 13: D²PAK package outline

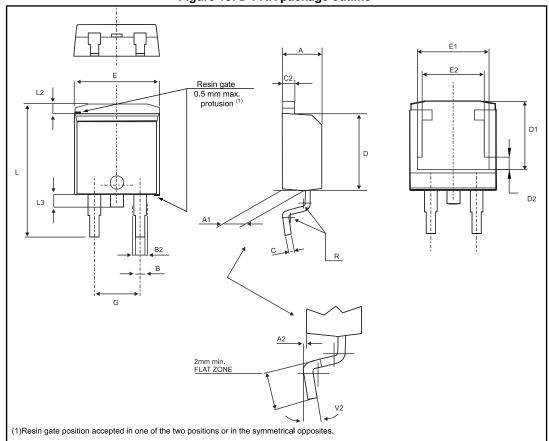


Table 6: D²PAK package mechanical data

			•	imensions		
Ref.		Millimeters			Inches ⁽¹⁾	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	4.30		4.60	0.1693		0.1811
A1	2.49		2.69	0.0980		0.1059
A2	0.03		0.23	0.0012		0.0091
В	0.70		0.93	0.0276		0.0366
B2	1.25	1.40		0.0492	0.0551	
С	0.45		0.60	0.0177		0.0236
C2	1.21		1.36	0.0476		0.0535
D	8.95		9.35	0.3524		0.3681
D1	7.50		8.00	0.2953		0.3150
D2	1.30		1.70	0.0512		0.0669
Е	10.00		10.28	0.3937		0.4047
E1	8.30		8.70	0.3268		0.3425
E2	6.85		7.25	0.2697		0.2854
G	4.88		5.28	0.1921		0.2079
L	15		15.85	0.5906		0.6240
L2	1.27		1.40	0.0500		0.0551
L3	1.40		1.75	0.0551		0.0689
R		0.40			0.0157	
V2	0°		8°	0°		8°

⁽¹⁾Dimensions in inches are given for reference only

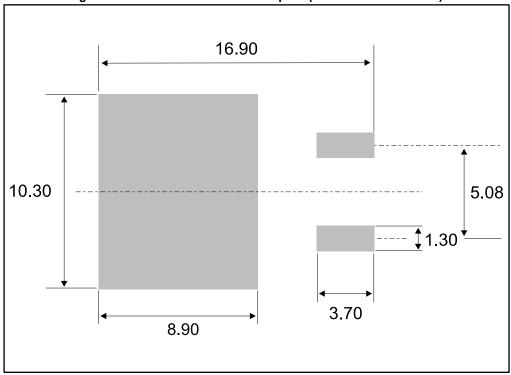


Figure 14: D²PAK recommended footprint (dimensions are in mm)



2.2 TO-220AB (NIns. and Ins.) package information

b1

(1)Resin gate position accepted in one of the two positions or in the symmetrical opposites.

Figure 15: TO-220AB (Nins. and Ins.) package outline

Μ

Resin gate 0.5 mm max. protusion⁽¹⁾

с1

Table 7: TO-220AB (NIns. and Ins.) package mechanical data

	Dimensions					
Ref.		Millimeters			Inches ⁽¹⁾	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	15.20		15.90	0.5984		0.6260
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5512
В	10.00		10.40	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0520
С	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0193		0.0276
c2	2.40		2.72	0.0945		0.1071
е	2.40		2.70	0.0945		0.1063
F	6.20		6.60	0.2441		0.2598
Ţ	3.73		3.88	0.1469		0.1528
L	2.65		2.95	0.1043		0.1161
12	1.14		1.70	0.0449		0.0669
13	1.14		1.70	0.0449		0.0669
14	15.80	16.40	16.80	0.6220	0.6457	0.6614
М		2.6			0.1024	

⁽¹⁾Inch dimensions are for reference only.

3 Ordering information

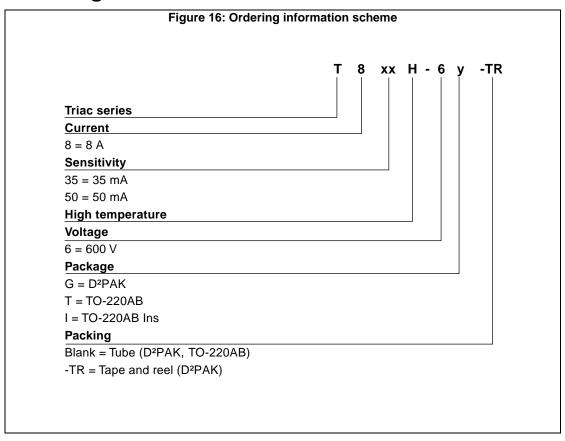


Table 8: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
T8xxH-6G	T8xxH 6G	D²PAK	1.5 g	50	Tube
T8xxH-6G-TR	T8xxH 6G	D²PAK	1.5 g	1000	Tape and reel
T8xxH-6T	T8xxH 6T	TO-220AB	2.3 g	50	Tube
T8xxH-6I	T8xxH 6I	TO-220AB Ins.	2.3 g	50	Tube

4 Revision history

Table 9: Document revision history

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Date	Revision	Changes		
17-Apr-2007	1	First issue.		
19-Sep-2011	2	Updated: Features, Description, Figure 2, Table 2 and 4.		
30-Mar-2017	3	Minor text changes. Updated <i>Table 4: "Static characteristics"</i> and <i>Figure 7: "Non-repetitive surge peak on-state current for a sinusoidal pulse".</i>		



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